NSN 5961-01-369-4052

Transistor - Page 1 of 1

A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-369-4052 **Inclosure Material:** Metal **Overall Length:** 0.055 inches **Overall Diameter:** 0.205 inches **Internal Configuration:** Junction contact-double emitter **Mounting Method:** Terminal **Features Provided:** Burn in and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage/static/emitter open and 24.0 collector to emitter voltage/static/base open and 3.3 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 200.00 nanoamperes zero-gate-voltage source current minor **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter and 75.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: